

# HiPerFET™ Power MOSFETs

N-Channel Enhancement Mode  
Avalanche Rated, High dv/dt, Low  $t_{rr}$

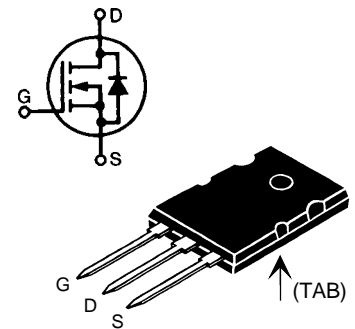
**IXFK 110 N06**  
**IXFK 105 N07**  
**IXFK 110 N07**

| $V_{DSS}$ | $I_{D25}$ | $R_{DS(on)}$ |
|-----------|-----------|--------------|
| 60 V      | 110 A     | 6 mΩ         |
| 70 V      | 105 A     | 7 mΩ         |
| 70 V      | 110 A     | 6 mΩ         |

$t_{rr} \leq 250 \text{ ns}$

| Symbol     | Test Conditions   | Maximum Ratings |              |                  |
|------------|---|-----------------|--------------|------------------|
| $V_{DSS}$  | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$   | N07             | 70           | V                |
| $V_{DGR}$  | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ ; $R_{GS} = 1 \text{ M}\Omega$  | N06             | 60           | V                |
| $V_{GS}$   | Continuous  | N07             | 70           | V                |
| $V_{GSM}$  | Transient   | N06             | 60           | V                |
| $I_{D25}$  | $T_C = 25^\circ\text{C}$ , die capability   |                 | 110          | A                |
| $I_{D130}$ | $T_C = 130^\circ\text{C}$ , limited by external leads   |                 | 76           | A                |
| $I_{DM}$   | $T_C = 25^\circ\text{C}$ , pulse width limited by $T_{JM}$  |                 | 600          | A                |
| $I_{AR}$   | $T_C = 25^\circ\text{C}$  |                 | 100          | A                |
| $E_{AR}$   | $T_C = 25^\circ\text{C}$  |                 | 30           | mJ               |
| $E_{AS}$   | $T_C = 25^\circ\text{C}$  |                 | 2            | J                |
| dv/dt      | $I_S \leq I_{DM}$ , $di/dt \leq 100 \text{ A}/\mu\text{s}$ , $V_{DD} \leq V_{DSS}$ ,<br>$T_J \leq 150^\circ\text{C}$ , $R_G = 2 \Omega$ |                 | 5            | V/ns             |
| $P_D$      | $T_C = 25^\circ\text{C}$  |                 | 500          | W                |
| $T_J$      |   |                 | -55 ... +150 | $^\circ\text{C}$ |
| $T_{JM}$   |   |                 | 150          | $^\circ\text{C}$ |
| $T_{stg}$  |   |                 | -55 ... +150 | $^\circ\text{C}$ |
| $T_L$      | 1.6 mm (0.063 in) from case for 10 s  |                 | 300          | $^\circ\text{C}$ |
| $M_d$      | Mounting torque   |                 | 0.9/6        | Nm/lb.in.        |
|            | Terminal connection torque  |                 | -            | Nm/lb.in.        |
| Weight     |   |                 | 10           | g                |

## TO-264 AA (IXFK)



## Features

- International standard packages
- JEDEC TO-264 AA, epoxy meet UL94 V-0, flammability classification
- Low  $R_{DS(on)}$  HDMOS™ process
- Rugged polysilicon gate cell structure
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
- Fast intrinsic Rectifier

## Applications

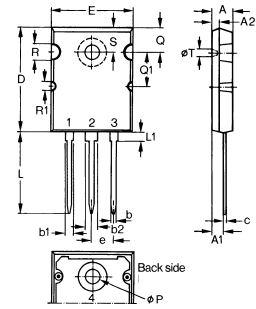
- DC-DC converters
- Synchronous rectification
- Battery chargers
- Switched-mode and resonant-mode power supplies
- DC choppers
- Temperature and lighting controls
- Low voltage relays

## Advantages

- Easy to mount
- Space savings
- High power density

| Symbol       | Test Conditions   | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |                           |
|--------------|---|---|------|---------------------------|
|              |   | min.  | typ. | max.                      |
| $V_{DSS}$    | $V_{GS} = 0 \text{ V}$ , $I_D = 1 \text{ mA}$                 | N06   | 60   | V                         |
|              |   | N07   | 70   | V                         |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 8 \text{ mA}$                      |   | 2    | 4 V                       |
| $I_{GSS}$    | $V_{GS} = \pm 20 \text{ V}_{DC}$ , $V_{DS} = 0$               |   |      | $\pm 200 \text{ nA}$      |
| $I_{DSS}$    | $V_{DS} = 0.8 \cdot V_{DSS}$ ,<br>$V_{GS} = 0 \text{ V}$      | $T_J = 25^\circ\text{C}$<br>$T_J = 125^\circ\text{C}$                             |      | 400 $\mu\text{A}$<br>2 mA |
| $R_{DS(on)}$ | $V_{GS} = 10 \text{ V}$ , $I_D = 0.5 \cdot I_{D25}$<br>Note 2 | 110N06/110N07<br>105N07   |      | 6 mΩ<br>7 mΩ              |

| Symbol       | Test Conditions  | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |      |
|--------------|--|---|------|------|
|              |  | min.  | typ. | max. |
| $g_{fs}$     | $V_{DS} = 10\text{ V}; I_D = 0.5 \cdot I_{D25}$ , Note 2   | 60  | 80   | S    |
| $C_{iss}$    | $V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$  |   | 9000 | pF   |
| $C_{oss}$    |  |   | 4000 | pF   |
| $C_{rss}$    |  |   | 2400 | pF   |
| $t_{d(on)}$  | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$<br>$R_G = 1\ \Omega$ (External), |   | 30   | ns   |
| $t_r$        |  |   | 60   | ns   |
| $t_{d(off)}$ |  |   | 100  | ns   |
| $t_f$        |  |   | 60   | ns   |
| $Q_{g(on)}$  | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$                                  |   | 480  | nC   |
| $Q_{gs}$     |  |   | 60   | nC   |
| $Q_{gd}$     |  |   | 240  | nC   |
| $R_{thJC}$   | TO-264 AA  |   | 0.25 | K/W  |
| $R_{thCK}$   | TO-264 AA  |   | 0.15 | K/W  |

**TO-264 AA Outline**


| Dim. | Millimeter |       | Inches |       |
|------|------------|-------|--------|-------|
|      | Min.       | Max.  | Min.   | Max.  |
| A    | 4.82       | 5.13  | .190   | .202  |
| A1   | 2.54       | 2.89  | .100   | .114  |
| A2   | 2.00       | 2.10  | .079   | .083  |
| b    | 1.12       | 1.42  | .044   | .056  |
| b1   | 2.39       | 2.69  | .094   | .106  |
| b2   | 2.90       | 3.09  | .114   | .122  |
| c    | 0.53       | 0.83  | .021   | .033  |
| D    | 25.91      | 26.16 | 1.020  | 1.030 |
| E    | 19.81      | 19.96 | .780   | .786  |
| e    | 5.46       | BSC   | .215   | BSC   |
| J    | 0.00       | 0.25  | .000   | .010  |
| K    | 0.00       | 0.25  | .000   | .010  |
| L    | 20.32      | 20.83 | .800   | .820  |
| L1   | 2.29       | 2.59  | .090   | .102  |
| P    | 3.17       | 3.66  | .125   | .144  |
| Q    | 6.07       | 6.27  | .239   | .247  |
| Q1   | 8.38       | 8.69  | .330   | .342  |
| R    | 3.81       | 4.32  | .150   | .170  |
| R1   | 1.78       | 2.29  | .070   | .090  |
| S    | 6.04       | 6.30  | .238   | .248  |
| T    | 1.57       | 1.83  | .062   | .072  |

| Symbol   | Test Conditions   | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |                   |
|----------|---|---|------|-------------------|
|          |   | min.  | typ. | max.              |
| $I_S$    | $V_{GS} = 0\text{ V}$   | 110N06/110N07<br>105N07   |      | 110 A<br>105 A    |
| $I_{SM}$ | Repetitive; pulse width limited by $T_{JM}$                                       | 110N06/110N07<br>105N07   |      | 440 A<br>420 A    |
| $V_{SD}$ | $I_F = 100\text{ A}, V_{GS} = 0\text{ V}$ , Note 2                                |   |      | 1.7 V             |
| $t_{rr}$ | $I_F = 25\text{ A}$<br>$-di/dt = 100\text{ A}/\mu\text{s}$<br>$V_R = 50\text{ V}$ |   | 150  | 250 ns            |
| $Q_{RM}$ |   |   |      | 0.7 $\mu\text{C}$ |
| $I_{RM}$ |   |   |      | 9 A               |

Note: 1. Pulse width limited by  $T_{JM}$   
2. Pulse test,  $t \leq 300\ \mu\text{s}$ , duty cycle  $d \leq 2\%$

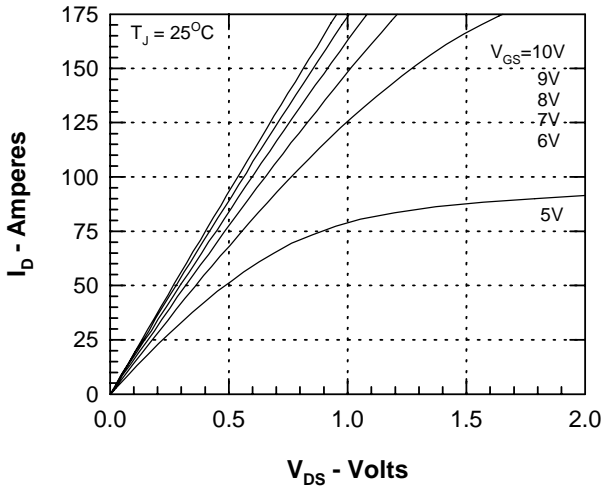


Figure 1. Output Characteristics at 25°C

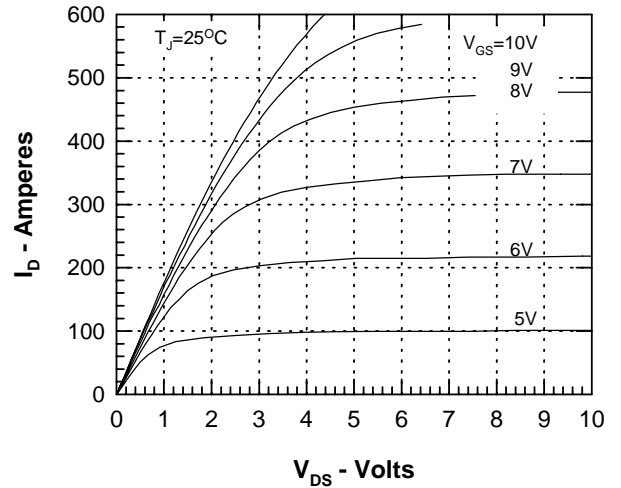


Figure 2. Extended Output Characteristics

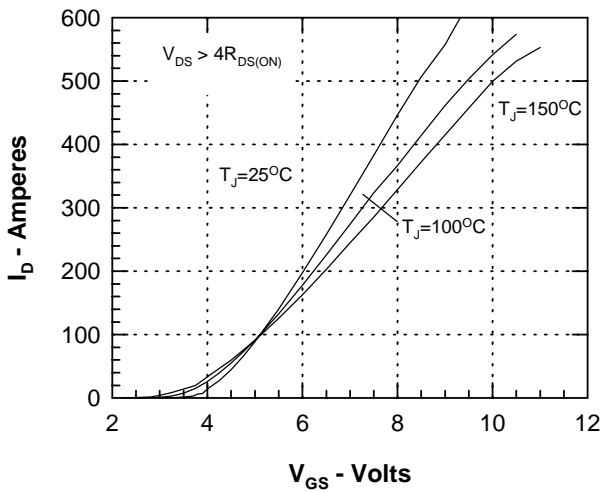


Figure 3. Admittance Curves

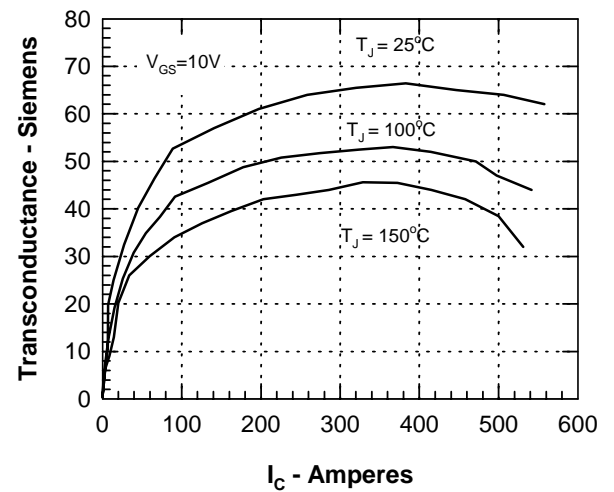
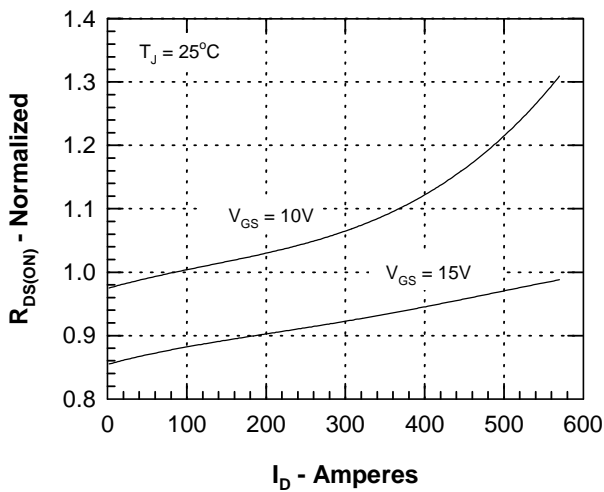
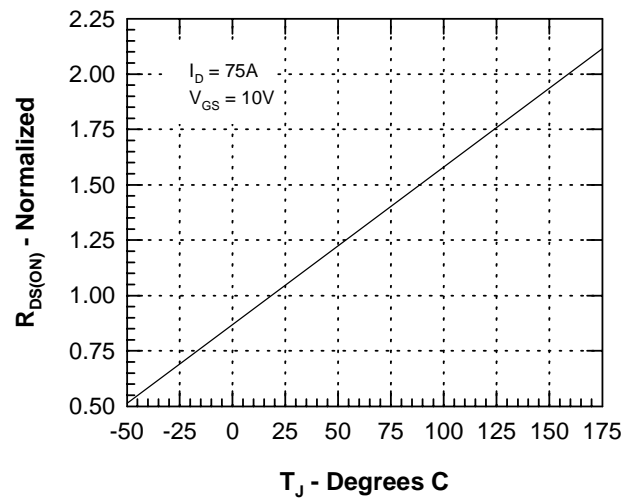


Figure 4. Transconductance vs. Drain Current


 Figure 5.  $R_{DS(on)}$  normalized to  $0.5 I_{D25}$  value

 Figure 6. Normalized  $R_{DS(on)}$  vs. Junction Temperature

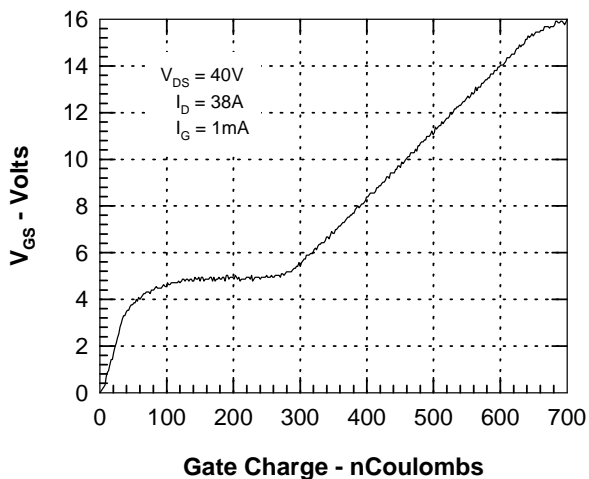


Figure 7. Gate Charge

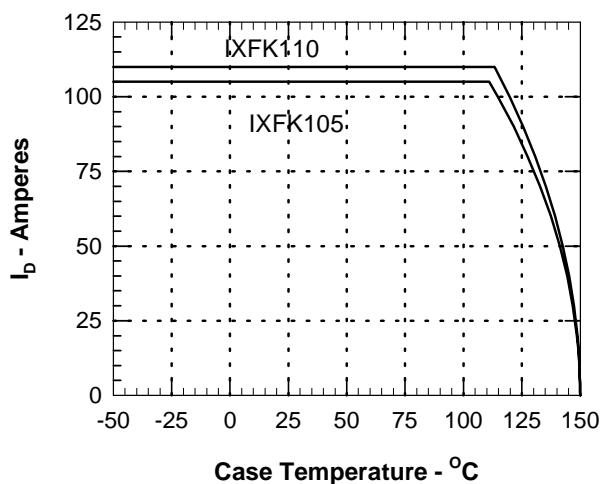


Figure 8. Drain Current vs. Case Temperature

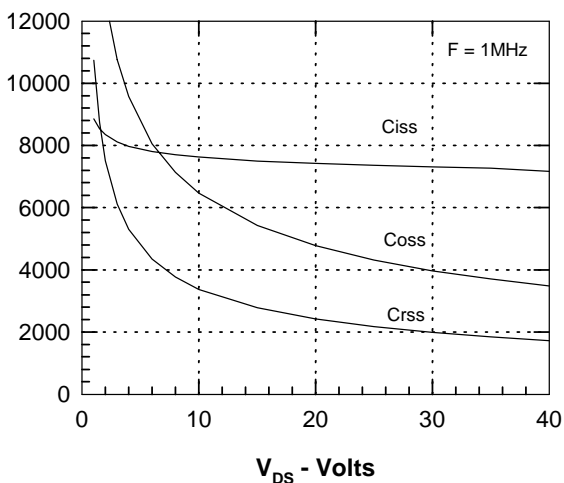


Figure 9. Capacitance Curves

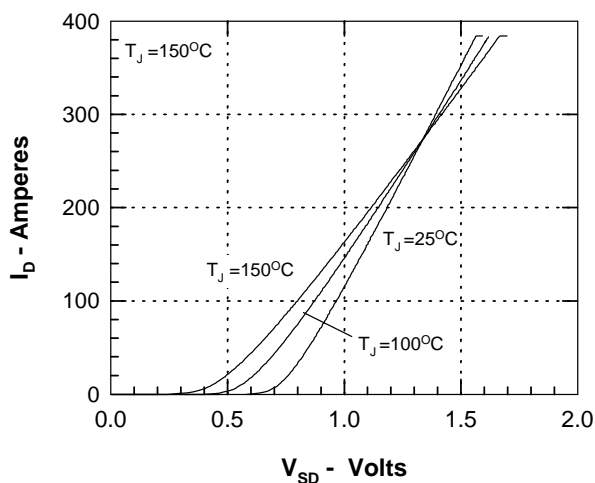


Figure 10. Source-Drain Voltage vs. Source Current

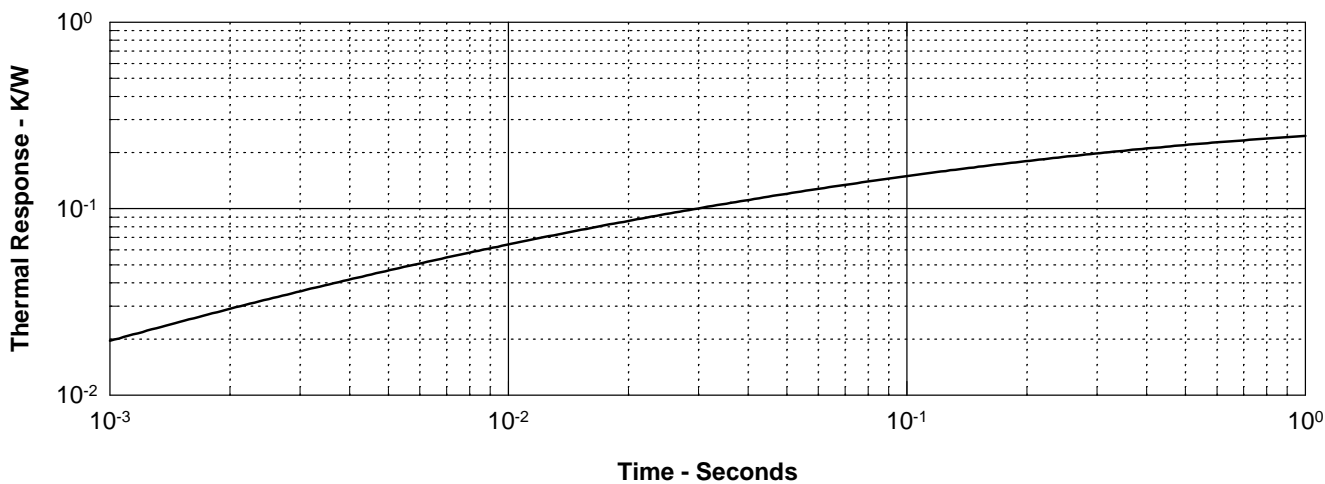


Figure 11. Transient Thermal Resistance



LittleDiode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

[LittleDiode.com](http://LittleDiode.com)

Looking forward to providing you with the best possible service.